



**100V N-CHANNEL ENHANCEMENT MODE VERTICAL MOSFET IN SOT223** 

#### **Features and Benefits**

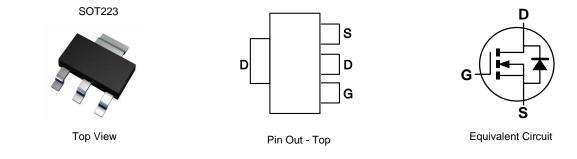
- $V_{(BR)DSS} > 100V$
- $R_{DS(ON)} \le 0.54\Omega @ V_{GS} = 10V$
- Maximum Continuous Drain Current ID = 1.67A
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

## Applications

- **DC-DC Converters**
- Solenoids / Relay Driver for Automotive

#### **Mechanical Data**

- Case: SOT223
- Case Material: Molded Plastic, "Green" Molding Compound; UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish (63)
- Weight: 0.112 grams (Approximate)



### Ordering Information (Note 4)

Part Number	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZVN4310GTA	ZVN4310	7	8	1,000

1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied. 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

## **Marking Information**

Notes:



4310

ZVN4310 = Product Type Marking Code YWW = Date Code Marking Y or  $\overline{Y}$  = Last Digit of Year (ex: 5= 2015) WW or  $\overline{W}W$  = Week Code (01~53)



## Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Drain-Source Voltage	V <sub>DSS</sub>	100	V
Gate-Source Voltage	V <sub>GSS</sub>	±20	V
Continuous Drain Current	I <sub>D</sub>	1.67	А
Pulsed Drain Current (Note 6)	I <sub>DM</sub>	12	А

## Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Power Dissipation	(Note 5)	PD	3	W
Thermal Resistance, Junction to Ambient	(Note 5)	R <sub>0JA</sub>	41.7	°C/W
Thermal Resistance, Junction to Leads	(Note 7)	R <sub>θJL</sub>	8.84	°C/W
Operating and Storage Temperature Range		T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

## Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)					•	·	
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	100	-	-	V	$V_{GS} = 0V, I_D = 1mA$	
Zero Gate Voltage Drain Current TJ = +25°C	IDSS	-	-	10	μΑ	$V_{DS} = 100V, V_{GS} = 0V$	
	1033			100	μA	$V_{DS} = 80V, V_{GS} = 0V, T_A = +125^{\circ}C$	
Gate-Source Leakage	I <sub>GSS</sub>	-	-	±20	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
On-State Drain Current	I <sub>D(ON)</sub>	9	-	-	Α	$V_{GS} = 10V, V_{DS} = 10V$	
ON CHARACTERISTICS (Note 8)							
Gate Threshold Voltage	V <sub>GS(TH)</sub>	1	-	3	V	$V_{DS} = V_{GS}$ , $I_D = 1mA$	
Static Drain-Source On-Resistance	Provenu	-	0.4 0.5	0.54	Ω	$V_{GS} = 10V, I_D = 3.3A$	
	R <sub>DS(ON)</sub>			0.75	32	$V_{GS} = 5V, I_D = 1.5A$	
Forward Transconductance	<b>g</b> fs	0.6	-	-	S	$V_{DS} = 10V, I_D = 3.3A$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	Ciss	-	-	350	pF		
Output Capacitance	Coss	-	-	140	pF	$V_{DS} = 25V, V_{GS} = 0V,$	
Reverse Transfer Capacitance	C <sub>rss</sub>	-	-	20	pF	f = 1.0MHz	
Turn-On Delay Time	t <sub>D(ON)</sub>	-	-	8	ns		
Turn-On Rise Time	t <sub>R</sub>	-	-	25	ns	V <sub>DD</sub> = 25V, I <sub>D</sub> = 3A, V <sub>GEN</sub> = 10V,	
Turn-Off Delay Time	t <sub>D(OFF)</sub>	-	-	30	ns	$R_{GS} = 50\Omega$	
Turn-Off Fall Time	t <sub>F</sub>	-	-	16	ns		

Notes: 5. For a device mounted on 50mm X 50mm X 1.6mm FR-4 PCB with high coverage of single sided 2oz copper, in still air condition.

6. Device mounted on minimum recommended pad layout test board, 10µs pulse duty cycle = 1%.

Thermal resistance from junction to solder-point (at the end of the drain lead).
Short duration pulse test used to minimize self-heating effect.



## **Electrical Characteristics**

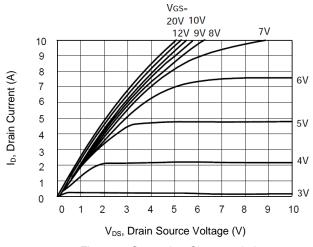


Figure 1. Saturation Characteristics

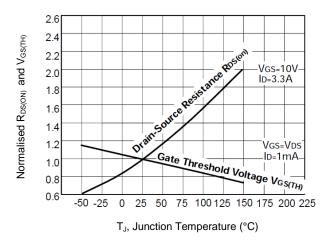
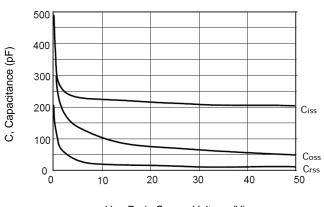


Figure 3. Normalised  $R_{DS(ON)}$  and  $V_{GS(TH)}$  vs. Temperature



 $V_{DS}$ , Drain Source Voltage (V)

Figure 5. Capacitance vs. Drain-source Voltage

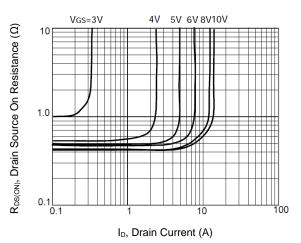


Figure 2. On-resistance vs. Drain Current

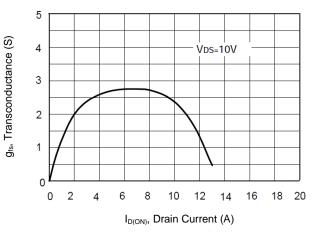


Figure 4. Transconductance vs. Drain Current

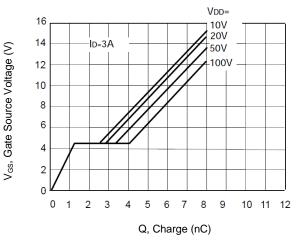
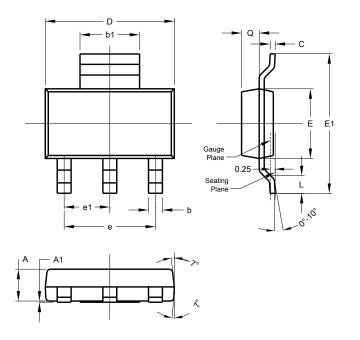


Figure 6. Gate Charge vs. Gate-source Voltage



## **Package Outline Dimensions**

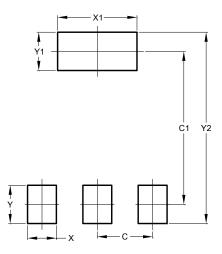
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



SOT223				
Dim	Min	Max	Тур	
Α	1.55	1.65	1.60	
A1	0.010	0.15	0.05	
b	0.60	0.80	0.70	
b1	2.90	3.10	3.00	
С	0.20	0.30	0.25	
D	6.45	6.55	6.50	
E	3.45	3.55	3.50	
E1	6.90	7.10	7.00	
е	-	-	4.60	
e1	-	-	2.30	
L	0.85	1.05	0.95	
q	0.84	0.94	0.89	
All Dimensions in mm				

## **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
С	2.30
C1	6.40
Х	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00



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